

SB1-266-1-5

Spec. #: SB1-21203

Microchip Laser



MAIN FEATURES

- 266 nm
- < 1.3 ns
- > 1 uJ
- Single Longitudinal Mode
- All-In-One Miniature Design

Technical Specifications		
Primary Output Wavelength	266	nm
Pulse Repetition Rate	5	kHz
Pulse energy	> 1	uJ
Pulse Width	< 1.3	ns
Peak Power	> 0.8	kW
Short Term Output Energy Instability (St.Dev. Over > 10000 samples)	< 3 %	
Long Term Output Power Instability (Power log over 24 hours)	< 5 %	
Beam Quality (M²)	< 1.5	
Output Beam Diameter at Exit		
Aperture (1/e2) without beam	< 2	mm
expander		
Secondary Output Wavelength	532nm (collinear to 266nm beam)	
Beam Ellipticity (axes ratio)	> 0.80	
Warm Up time after cold start	< 5	min
Power Consumption	< 20	W
Mechanical Package	SB1	
Operational Temperature Range	+10°C to +40°C	
Storage Temperature Range	-20°C to +60°C	

All information included in this document are subject to change without notice. Updated data sheets can be provided on request.

For further details, please contact your local **Bright Microlaser** sales representative or visit our website at www.brightmicrolaser.com

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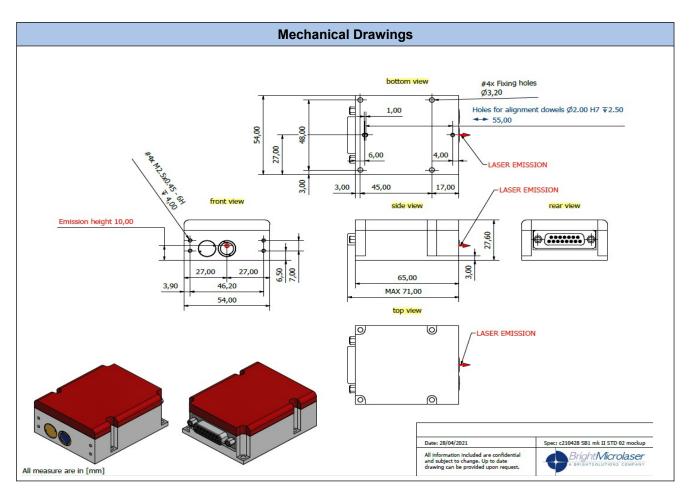
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Options Available:

- Beam Expander and Collimator
- Heat-sink
- Development kit
- Quick start/evaluation kit

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